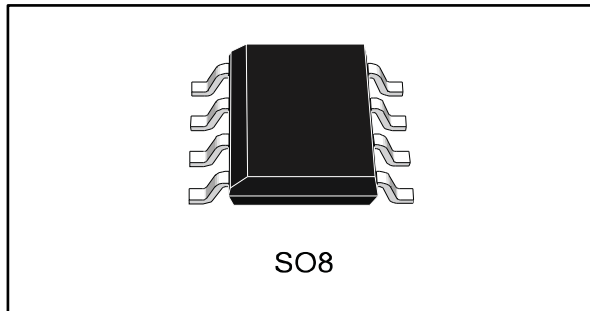


3.3 V powered, 15 kV ESD protected, up to 12 Mbps RS-485/
RS-422 transceiver

Datasheet - production data



Features

- ESD protection
 - ±15 kV IEC 61000-4-2 air discharge
 - ±8 kV IEC 61000-4-2 contact discharge
- Operate from a single 3.3 V supply - no charge pump required
- Interoperable with 5 V logic
- 1 µA low current shutdown mode max.
- Guaranteed 12 Mbps data rate
- -7 to 12 V common mode input voltage range
- Half duplex versions available
- Industry standard 75176 pinout

- Current limiting and thermal shutdown for driver overload protection
- Guaranteed high receiver output state for floating inputs with no signal present
- Allow up to 64 transceivers on the bus
- Available in SO8 package
- Automotive grade (ST3485EIY)

Description

The ST3485EB/EC/EI/EIY device is ±15 kV ESD protected, 3.3 V low power transceiver for RS-485 and RS-422 communications. The device contains one driver and one receiver in half duplex configuration.

The ST3485E device transmits and receives at a guaranteed data rate of at least 12 Mbps.

All transmitter outputs and receiver inputs are protected to ±15 kV IEC 61000-4-2 air discharge.

The driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high impedance state.

Table 1: Device summary

Order code	Temp. range	Package	Packing
ST3485ECDR	0 to 70 °C	SO8 (tape and reel)	2500 parts per reel
ST3485EBDR	-40 to 85 °C		
ST3485EIDT	-40 to 125 °C		
ST3485EIYDT			

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1 Pin configuration

Figure 1: Pin connections

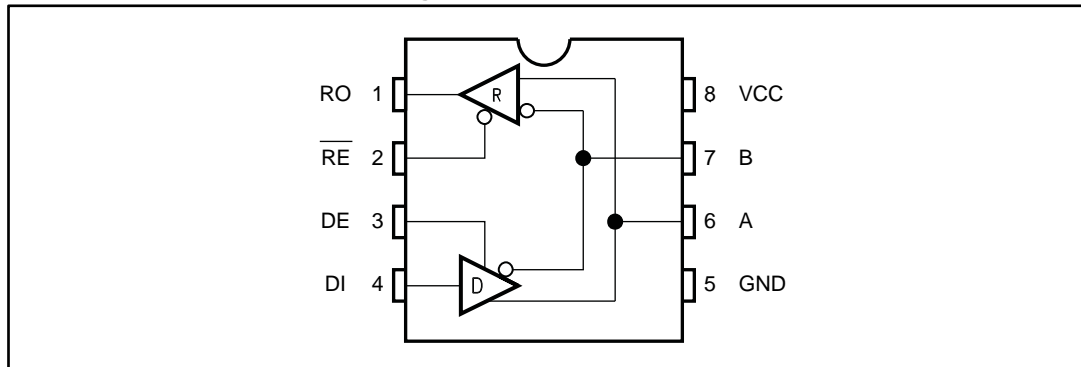


Table 2: Pin description

Pin n°	Symbol	Name and function
1	RO	Receiver output. If $A > B$ by 200 mV, RO will be high; if $A < B$ by 200 mV, RO will be low.
2	\overline{RE}	Receiver output enable. RO is enabled when \overline{RE} is low; RO is high impedance when \overline{RE} is high. If \overline{RE} is high and DE is low, the device will enter a low power shutdown mode.
3	DE	Driver output enable. The driver outputs are enabled by bringing DE high. They are high impedance when DE is low. If \overline{RE} is high DE is low, the device will enter a low-power shutdown mode. If the driver outputs are enabled, the part functions as line driver, while they are high impedance, it functions as line receivers if \overline{RE} is low.
4	DI	Driver input. A low on DI forces output A low and output B high. Similarly, a high on DI forces output A high and output B low.
5	GND	Ground.
6	A	Non-inverting receiver input and non-inverting driver output.
7	B	Inverting receiver input and inverting driver output.
8	VCC	Supply voltage: $V_{CC} = 3\text{ V to }3.6\text{ V}$.

2 Truth tables

Table 3: Truth table (driver)

Inputs			Outputs		Mode
\overline{RE}	DE	DI	B	A	
X	H	H	L	H	Normal
		L	H	L	
L	L	X	Z	Z	
H					

Note: X = "don't care"; Z = high impedance

Table 4: Truth table (receiver)

Inputs			Output	Mode
\overline{RE}	DE	A-B	RO	
L	L	$\geq 0.2\text{ V}$	H	Normal
		$\leq -0.2\text{ V}$	L	
		Inputs open	H	
H		X	Z	Shutdown

Note: X = "don't care"; Z = high impedance

3 Maximum ratings

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 5: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	7	V
V_I	Control input voltage (\overline{RE} , DE)	-0.3 to 7	
V_{DI}	Driver input voltage (DI)	-0.3 to 7	
V_{DO}	Driver output voltage (A, B)	± 14	
V_{RI}	Receiver input voltage (A, B)	± 14	
V_{RO}	Receiver output voltage (RO)	-0.3 to ($V_{CC} + 0.3$)	
ESD	HBM: human body model for the line inputs (A and B) ⁽¹⁾	12	kV
	HBM: human body model for the logic inputs (DI, DE, \overline{RE}) ⁽¹⁾	4	
	HBM: human body model for all other pins ⁽¹⁾	2	
	CDM: charged device model ⁽²⁾	1.5	

Notes:

⁽¹⁾Human body model: 100 pF discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

⁽²⁾Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.

4 Electrical characteristics

Table 6: Electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
ISUPPLY	VCC power supply current	No load, DI = 0 V or VCC	—	DE = VCC, $\overline{RE} = 0$ V or VCC	1.3	2.2	mA
				DE = 0 V, $\overline{RE} = 0$ V	1.2	1.9	
ISHDN	Shutdown supply current	DE = 0 V, $\overline{RE} = V_{CC}$, DI = 0 V or VCC		0.002	1	μA	

Table 7: Logic input electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
VIL	Input logic threshold low	DE, DI, \overline{RE}		1.3	0.8	V
VIH	Input logic threshold high	DE, DI, \overline{RE}	2			
IIN1	Logic input current	DE, DI, \overline{RE}			±2.0	μA
IIN2	Input current (A, B)	DE = 0 V, VCC = 0 or 3.6 V	VIN = 12 V		1	mA
			VIN = -7 V		-0.8	

Table 8: Transmitter electrical characteristics ($V_{CC} = 3\text{ V to }3.6\text{ V}$, $T_A = 0\text{ to }70\text{ °C}$ for ST3485ECDR, $T_A = -40\text{ to }85\text{ °C}$ for ST3485EBDR, $T_A = -40\text{ to }125\text{ °C}$ for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to $T_A = 25\text{ °C}$)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit		
V_{OD}	Differential drive output	$R_L = 100\ \Omega$ (RS-422) (Figure 2)	2	—	0.2	V		
		$R_L = 54\ \Omega$ (RS-485) (Figure 2)	1.5					
		$R_L = 60\ \Omega$ (RS-485) (Figure 3)	1.5					
ΔV_{OD}	Change in magnitude of driver differential output voltage for complementary output states ⁽¹⁾	$R_L = 54\ \Omega$ or $100\ \Omega$ (Figure 2)						
V_{OC}	Driver common mode output voltage	$R_L = 54\ \Omega$ or $100\ \Omega$ (Figure 2)						3
ΔV_{OC}	Change in magnitude of driver common mode output voltage ⁽¹⁾	$R_L = 54\ \Omega$ or $100\ \Omega$ (Figure 2)						0.2
I_{OSD}	Driver short-circuit output current				± 250	mA		

Notes:

⁽¹⁾ ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.

Table 9: Receiver electrical characteristics ($V_{CC} = 3\text{ V to }3.6\text{ V}$, $T_A = 0\text{ to }70\text{ °C}$ for ST3485ECDR, $T_A = -40\text{ to }85\text{ °C}$ for ST3485EBDR, $T_A = -40\text{ to }125\text{ °C}$ for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to $T_A = 25\text{ °C}$)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{TH}	Receiver differential threshold voltage	$V_{CM} = -7\text{ V to }12\text{ V}$, $DE = 0$	-0.2		0.2	V
ΔV_{TH}	Receiver input hysteresis	$V_{CM} = 0\text{ V}$		70		mV
V_{OH}	Receiver output high voltage	$I_{OUT} = -4\text{ mA}$, $V_{ID} = 200\text{ mV}$ (Figure 4)	2			V
V_{OL}	Receiver output low voltage	$I_{OUT} = 4\text{ mA}$, $V_{ID} = -200\text{ mV}$ (Figure 4)			0.4	
I_{OZR}	3-state (high impedance) output current at receiver	$V_{CC} = 3.6\text{ V}$, $V_O = 0\text{ V to }V_{CC}$			± 1	μA
R_{RIN}	Receiver input resistance	$V_{CM} = -7\text{ V to }12\text{ V}$	24			k Ω
I_{OSR}	Receiver short-circuit current	$V_{RO} = 0\text{ V to }V_{CC}$	7		60	mA

Table 10: Driver switching characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
D _R	Maximum data rate		12	15		Mbps
t _{DD}	Differential output delay	R _L = 60 Ω, C _L = 15 pF (Figure 5 and Figure 6)		18	30	ns
t _{TD}	Differential output transition time	R _L = 60 Ω, C _L = 15 pF (Figure 5 and Figure 6)		12	20	
t _{PLH} t _{PHL}	Propagation delay	R _L = 27 Ω, C _L = 15 pF (Figure 9 and Figure 10)		18	30	
t _{PDS}	t _{PLH} - t _{PHL} driver propagation delay skew ⁽¹⁾	R _L = 27 Ω, C _L = 15 pF (Figure 9 and Figure 10)		2	5	
t _{PZL}	Output enable time	R _L = 110 Ω (Figure 11 and Figure 12)		19	35	
t _{PZH}	Output enable time	R _L = 110 Ω (Figure 7 and Figure 8)		30	50	
t _{PHZ}	Output disable time	R _L = 110 Ω (Figure 7 and Figure 8)		19	35	
t _{PLZ}	Output disable time	R _L = 110 Ω (Figure 11 and Figure 12)		30	50	
t _{SKEW}	Differential output delay skew			1	3	
t _{PSH}	Driver enable from shutdown to output high	R _L = 110 Ω (Figure 7 and Figure 8)		30	50	
t _{PSL}	Driver enable from shutdown to output low	R _L = 110 Ω (Figure 11 and Figure 12)		19	35	

Notes:

⁽¹⁾Measured on |t_{PLH}(A)-t_{PHL}(A)| and |t_{PLH}(B)-t_{PHL}(B)|.

Table 11: Receiver switching characteristics ($V_{CC} = 3\text{ V to }3.6\text{ V}$, $T_A = 0\text{ to }70\text{ }^\circ\text{C}$ for ST3485ECDR, $T_A = -40\text{ to }85\text{ }^\circ\text{C}$ for ST3485EBDR, $T_A = -40\text{ to }125\text{ }^\circ\text{C}$ for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to $T_A = 25\text{ }^\circ\text{C}$)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t_{RPLH} , t_{RPHL}	Propagation delay	$V_{ID} = 0\text{ V to }3\text{ V}$, $C_L = 15\text{ pF}$ (Figure 13 and Figure 14)	—	30	50	ns
t_{RPDS}	$ t_{RPLH} - t_{RPHL} $ receiver propagation delay skew	$V_{ID} = 0\text{ V to }3\text{ V}$, $C_L = 15\text{ pF}$ (Figure 13 and Figure 14)		1	3	
t_{PRZL}	Receiver output enable time to low level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 17)		10	20	
t_{PRZH}	Receiver output enable time to high level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 16)		10	20	
t_{PRHZ}	Receiver output disable time from high level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 18)		10	20	
t_{PRLZ}	Receiver output disable time from low level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 19)		10	20	
t_{PRSH}	Receiver output enable time from shutdown to high level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 16)		10	20	
t_{PRSL}	Receiver output enable time from shutdown to low level	$C_L = 15\text{ pF}$ (Figure 15 and Figure 17)		20	40	μs

Notes:

- ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.
- Measured on $|t_{PLH}(A) - t_{PHL}(A)|$ and $|t_{PLH}(B) - t_{PHL}(B)|$.
- The transceivers are put into shutdown by bring \overline{RE} high and DE low. If the input are in state for less than 80 ns, the part are guaranteed not to enter shutdown. If the inputs are in this state for at least 300 ns, the parts are guaranteed to have entered shutdown.

5 Test circuits and typical characteristics

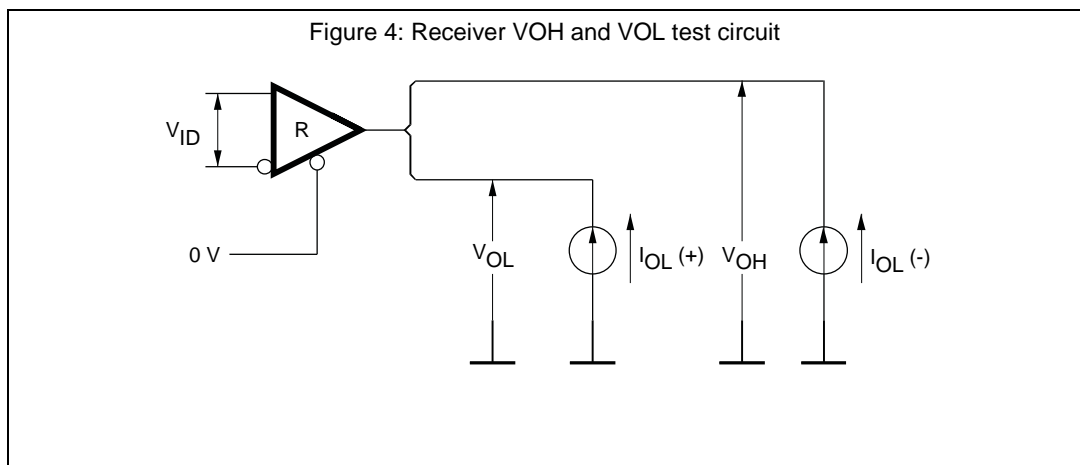
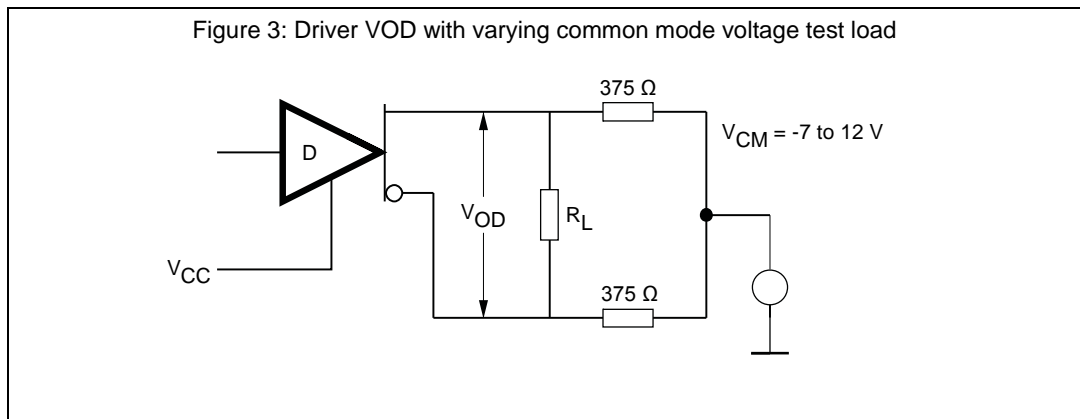
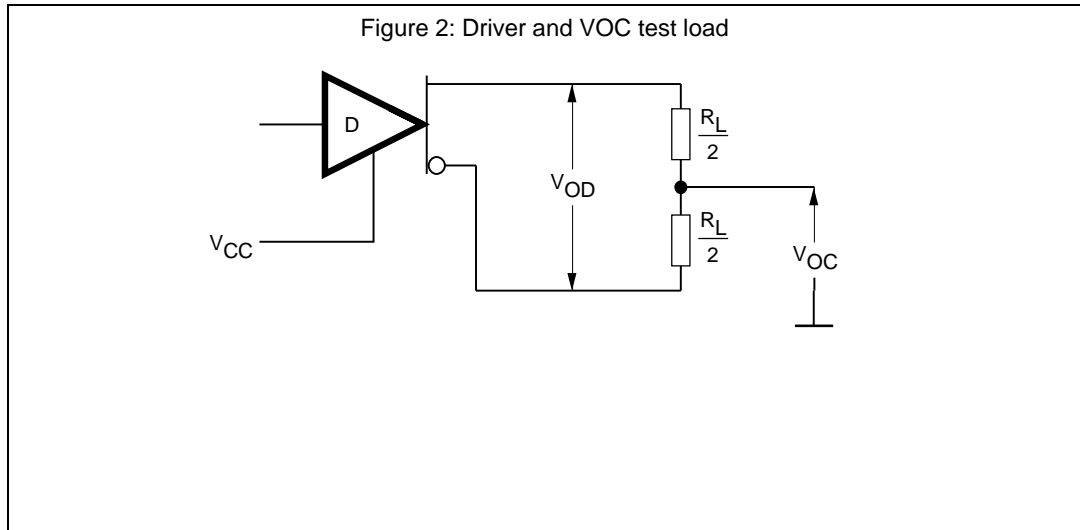
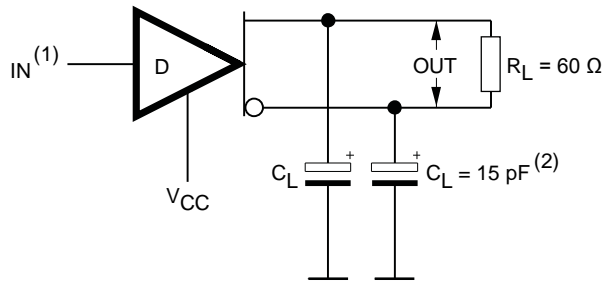


Figure 5: Drive differential output delay transition time test circuit



1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0$ ns, $Z_o = 50 \Omega$.
2. C_L includes probe and stray capacitance

Figure 6: Drive differential output delay transition time waveform

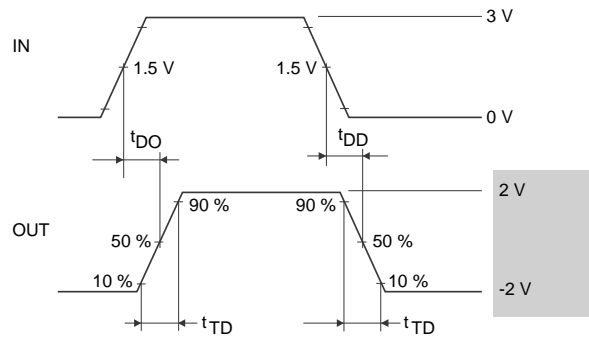
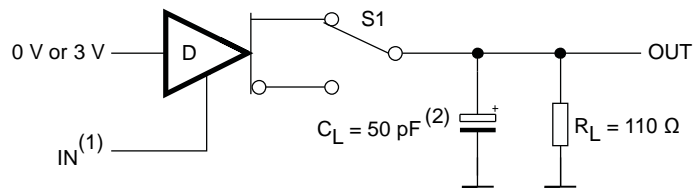
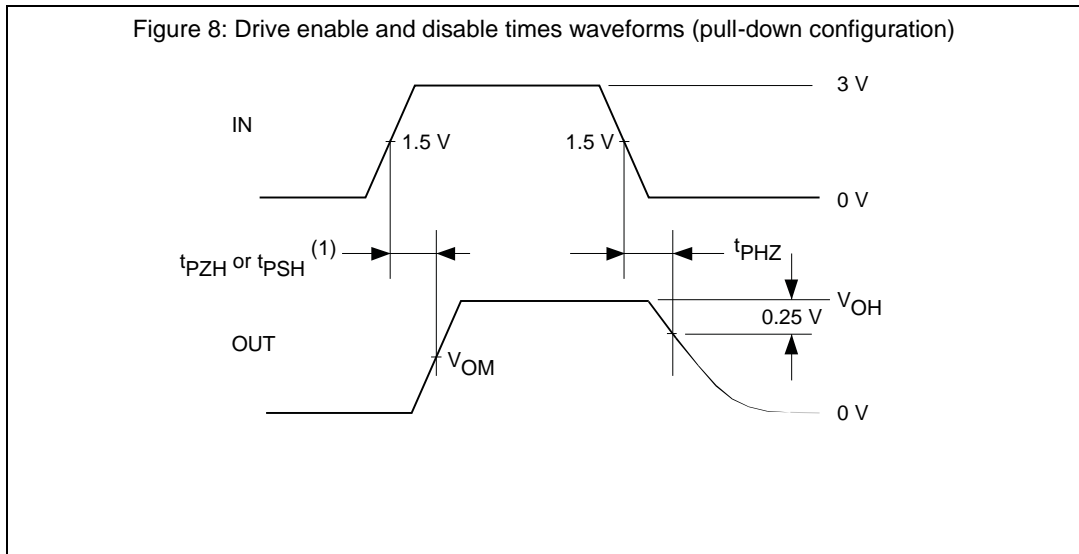


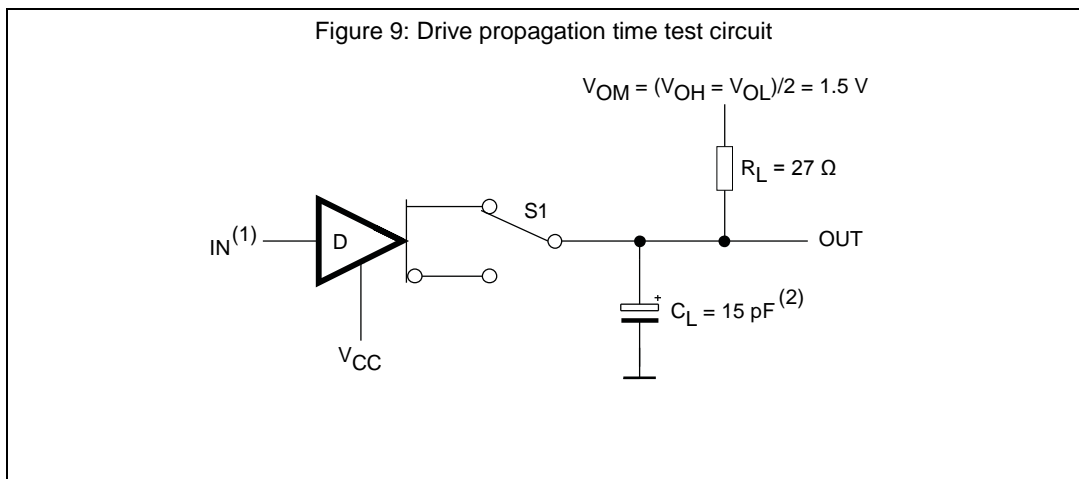
Figure 7: Drive enable and disable times test circuit (pull-down configuration)



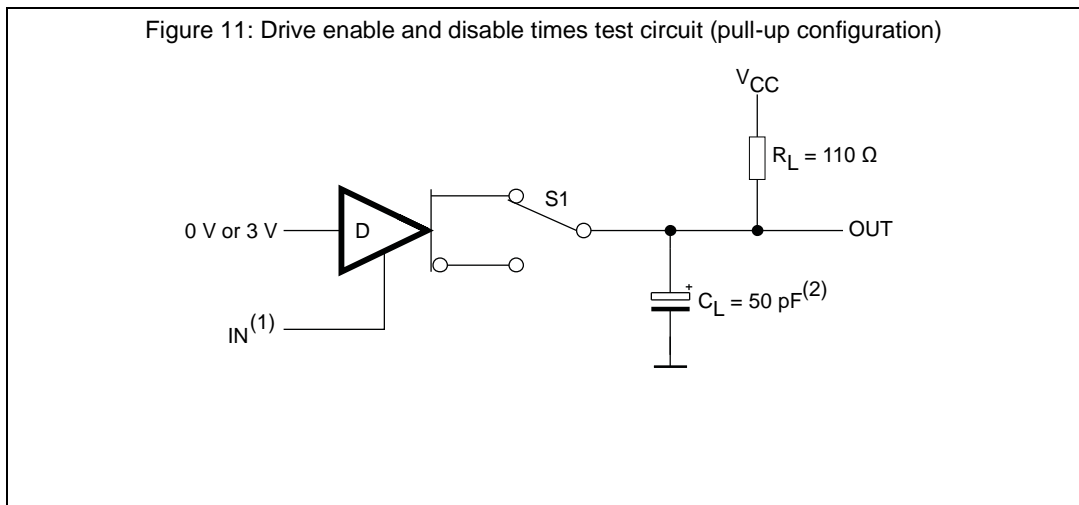
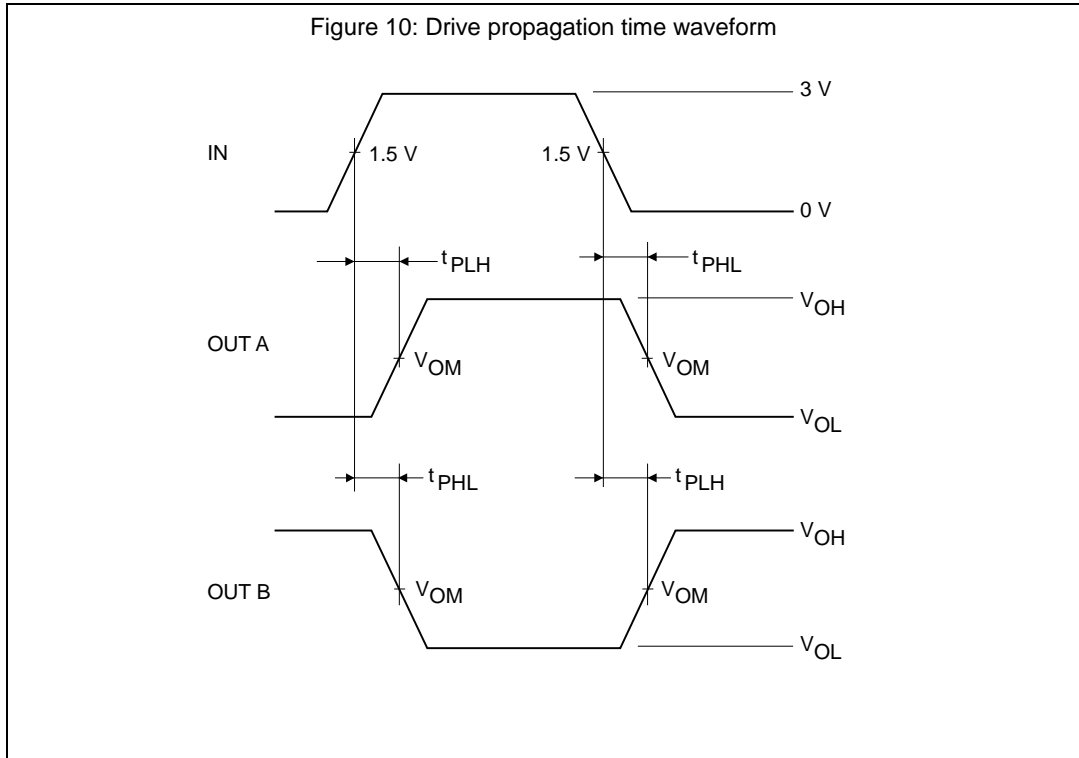
1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0$ ns.
2. C_L includes probe and stray capacitance



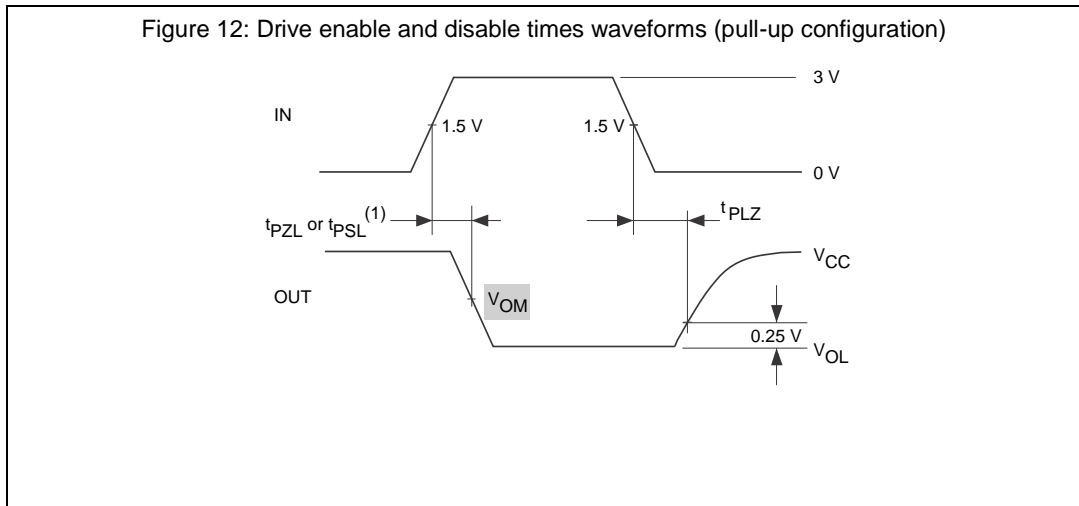
1. t_{PZH} is valid if the driver is initially disabled (\overline{RE} is high), t_{PSH} is valid if the driver is initially in shutdown mode (RE is low).



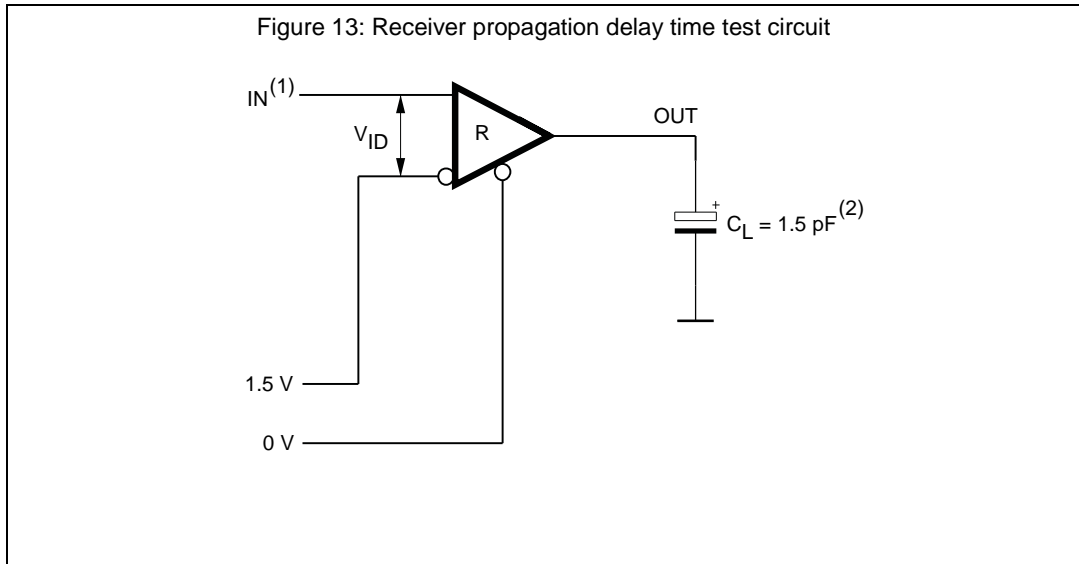
1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0 \text{ ns}$.
2. C_L includes probe and stray capacitance



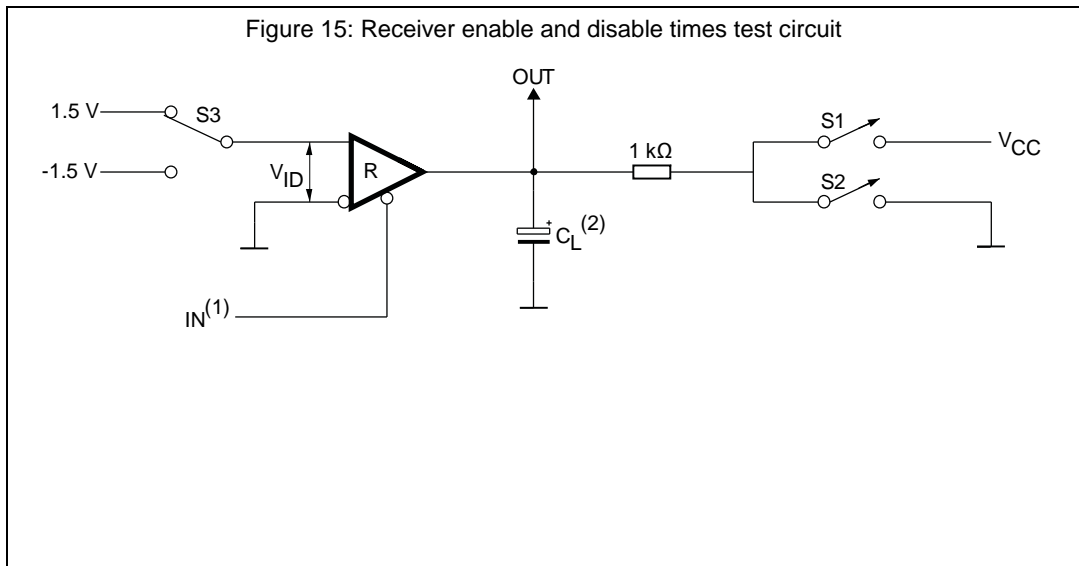
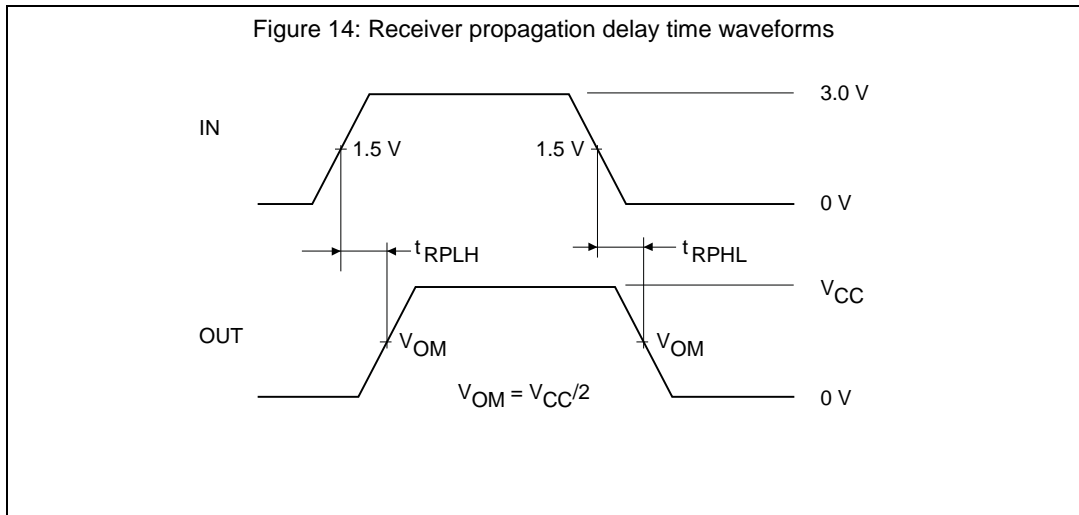
1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0 \text{ ns}$.
2. C_L includes probe and stray capacitance



1. t_{PZL} is valid if the driver is initially disabled (\overline{RE} is high), t_{PSL} is valid if the driver is initially in shutdown mode (RE is low).



1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0$ ns.
2. C_L includes probe and stray capacitance



1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, $t_r \leq 6.0$ ns.
2. C_L includes probe and stray capacitance

Figure 16: Receiver enable and disable times waveform (test 1)

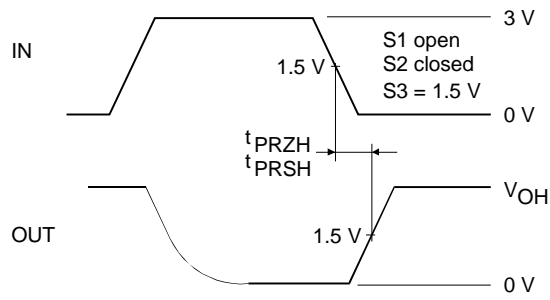


Figure 17: Receiver enable and disable times waveform (test 2)

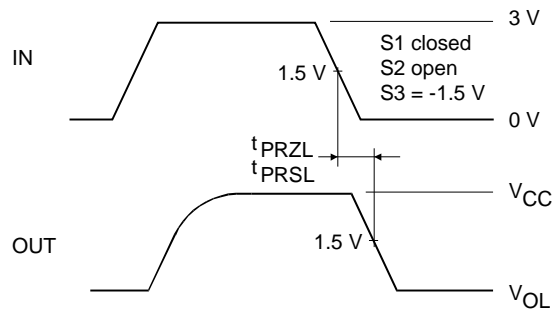


Figure 18: Receiver enable and disable times waveform (test 3)

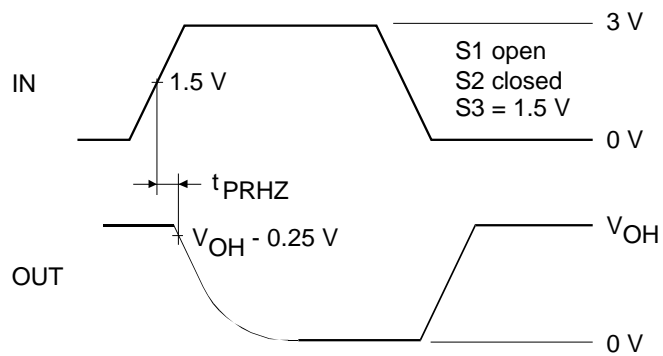


Figure 19: Receiver enable and disable times waveform (test 4)

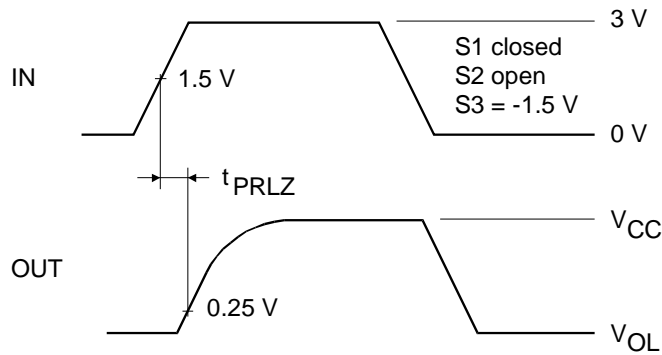


Figure 20: Receiver output current vs. output low voltage

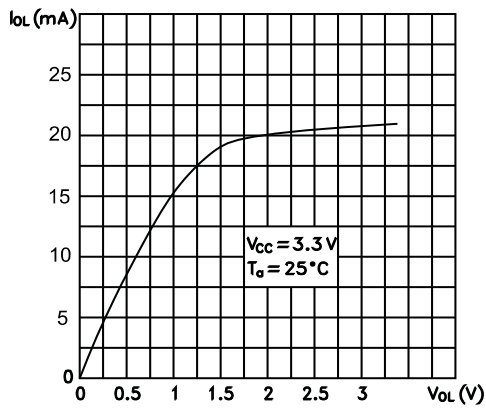


Figure 21: Receiver output current vs. output high voltage

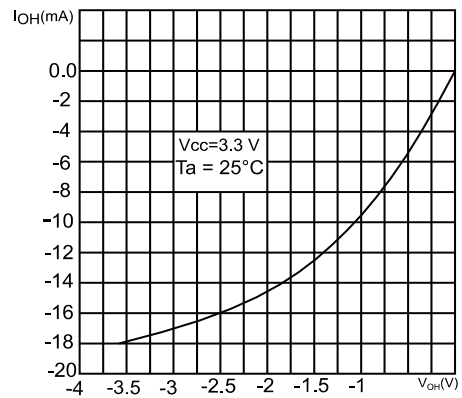


Figure 22: Low level driver output capability

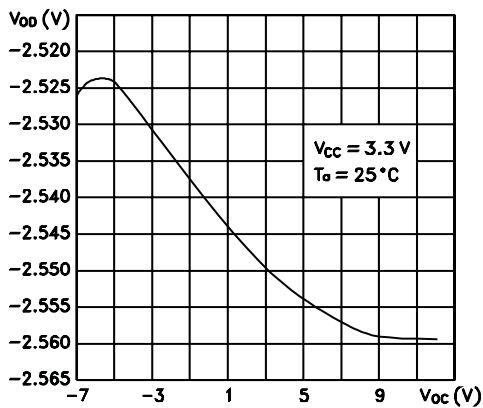


Figure 23: High level driver output capability

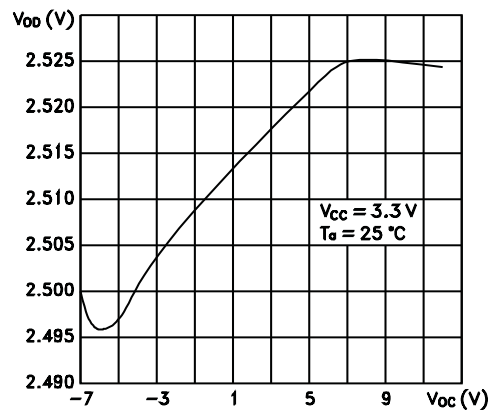


Figure 24: Receiver input characteristics

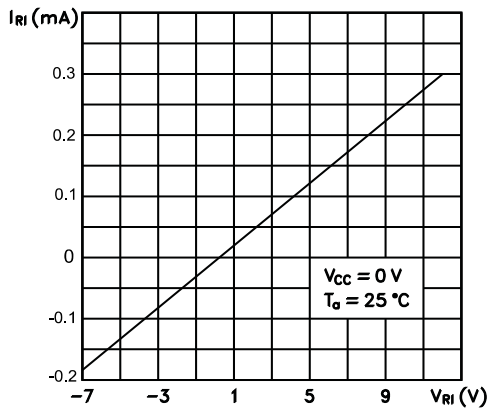


Figure 25: Driver short-circuit current (test 1)

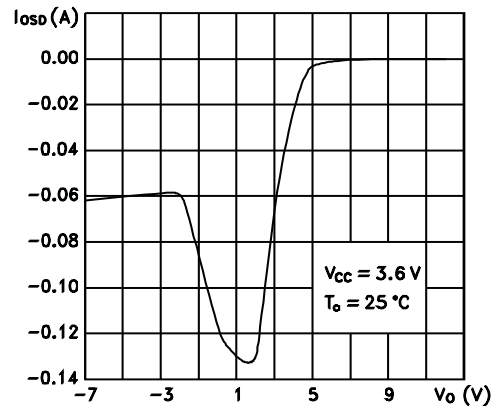
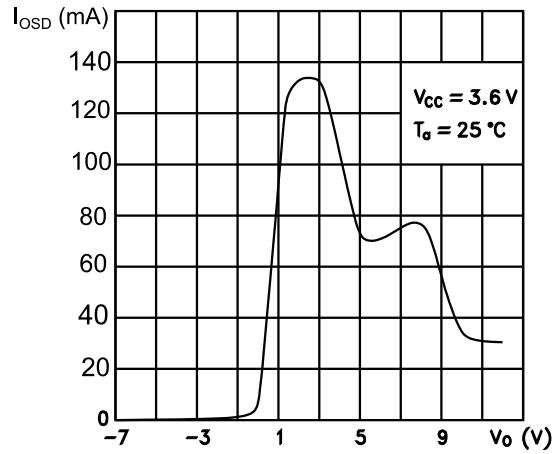


Figure 26: Driver short-circuit current (test 2)



6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

6.1 SO8 package information

Figure 27: SO8 package outline

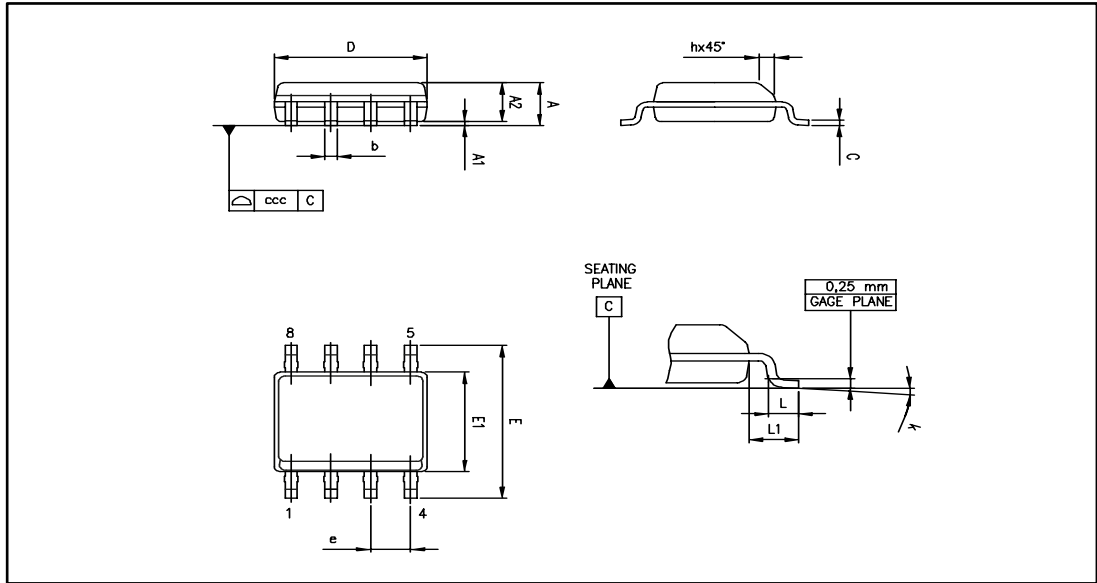
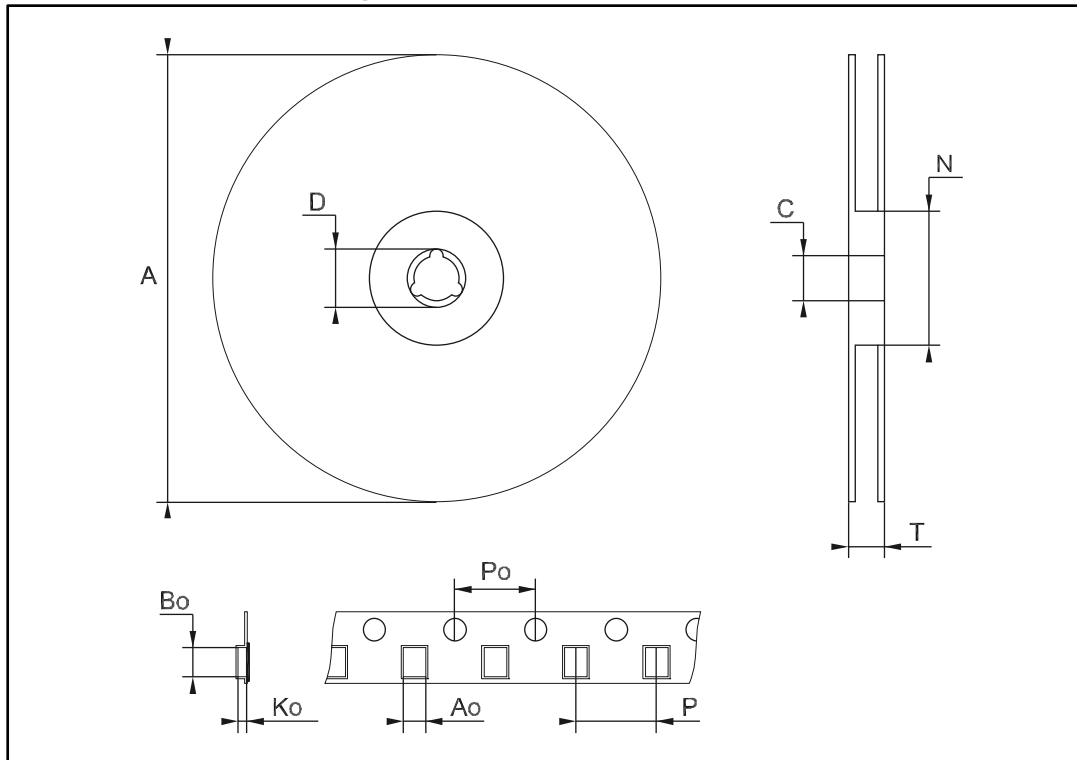


Table 12: SO8 mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0°		8°	0°		8°
ccc			0.10			0.004

6.2 SO8 tape and reel information

Figure 28: SO8 tape and reel outline



1. Drawing not to scale

Table 13: SO8 tape and reel mechanical data

Symbol	Dimensions					
	mm			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	8.1	—	8.5	0.319	—	0.335
Bo	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319

7 Ordering information

Table 14: Order codes

Order code	Temperature range	Package	Packaging	Marking
ST3485ECDR	0 to 70 °C	SO8	Tape and reel	3485EC
ST3485EBDR	-40 to 85 °C			3485EB
ST3485EIDT	-40 to 125 °C			3485EI
ST3485EIYDT ⁽¹⁾	-40 to 125 °C (automotive grade)			3485EIY

Notes:

⁽¹⁾Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.

8 Revision history

Table 15: Document revision history

Date	Revision	Changes
20-Jun-2005	2	Mistake on table 12 $t_{ZL(SHDN)}$ ms ==> μ s.
30-Aug-2005	3	Remove (TRUE) on title, description has been updated in cover page. The V_{TH} and DV_{TH} values are changed in table 10.
07-Apr-2006	4	Order codes updated.
12-Nov-2007	5	Added Table 1.
18-Dec-2013	6	<p>Updated Features (added SO-8 package, replaced human body model by ± 15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2).</p> <p>Updated Description (renamed device to ST3485EB/EC, replaced human body model by ± 15 kV IEC 61000-4-2 air discharge).</p> <p>Removed ST3485ECN device from Table 1.</p> <p>Updated title of Table 6, cross-references, replaced human body model (HBM) by ± 15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2.</p> <p>Added notes below Table 9.</p> <p>Updated Table 10 to Table 12 (updated data, cross-references).</p> <p>Updated Figure 5 to Figure 16 (updated data, added notes below figures and highlighted some parts of Figure 6 and Figure 12).</p> <p>Removed DIP-8 package from Section 6: "Package information" and whole document. Reformatted Section 6: "Package information" (added Figure 27, Figure 28, Table 13 and Table 14, reversed order of figures and table).</p> <p>Minor corrections throughout document.</p>
12-Jun-2015	7	<p>Added part number ST3485EIY</p> <p>Added order code ST3485EIYDT and pointed out in Features it is automotive grade.</p> <p>Table 7 and Table 9 through to Table 12: replaced $T_A = -40$ to 85 °C with $T_A = 0$ to 70 °C (ST3485ECCR), $T_A = -40$ to 85 °C (ST3485EBDR), and $T_A = -40$ to 125 °C (ST3485EIYDT).</p> <p>Updated titles of figures 7, 8, 11, 12, 16, 17, 18, 19, 25, and 26</p>
15-Mar-2016	8	<p>Table 5: added ESD information</p> <p>Removed "Table 6: ESD performance: transmitter outputs, receiver inputs (A, B)".</p> <p>Added Section 7: "Ordering information"</p>
02-Aug-2016	9	<p>Added new part number ST3485EI</p> <p>Table 1: "Device summary": added information for new part number ST3485EI.</p> <p>Removed "Note" icons throughout datasheet</p> <p>Section 4: "Electrical characteristics": updated T_A information</p> <p>Section 5: "Test circuits and typical characteristics": removed overline bar concerning "RE is low" in note 1 of figures 8 and 12.</p> <p>Table 14: "Order codes": added ST3485EIDT and updated footnote 1 (ST3485EIYDT now qualified).</p>
25-Aug-2016	10	Table 14: "Order codes": updated order codes ST3485EBDR and ST3485ECCR.

Date	Revision	Changes
26-Oct-2017	11	Updated <i>Figure 20: "Receiver output current vs. output low voltage"</i> , <i>Figure 21: "Receiver output current vs. output high voltage"</i> , <i>Figure 24: "Receiver input characteristics"</i> and <i>Figure 26: "Driver short-circuit current (test 2)"</i> .

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